

Supplementary material

Core-Shell Cu@Cu₂O Nanoparticles Embedded in 3D Honeycomb-like N-Doped Graphitic

Carbon for Photocatalytic CO₂ Reduction

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Time-resolved transient PL measurement

Fluorescence lifetime and steady-state spectrometer (FLs980, Edinburgh Instruments, UK) was used to test the steady-state lifetime photoluminescence (PL) spectrum and time-resolved photoluminescence (TRPL) spectrum, and the excitation wavelength was 384 nm. The emission decay data were fitted to a double-exponential model and the emission decay behavior is deduced through Eq. (1)

$$\tau_{\text{avg.}} = \frac{A_1\tau_1^2 + A_2\tau_2^2}{A_1\tau_1 + A_2\tau_2} \quad (1)$$

where τ and A are the decay time and the relative magnitude of components, respectively, and $\tau_{\text{avg.}}$ is the intensity-averaged lifetime used for an overall comparison. The fitting results show the fast decay component (τ_1 and A_1) and the minority-slow component (τ_2 and A_2), decaying from the free excited states and the bound excited states, respectively.

CO₂ Product Selectivity Calculation:

According to the electron transfer number for producing each reduction product (8e⁻ for CH₄ and 2e⁻ for CO), the selectivity of CH₄ is defined as follows:¹

$$\text{CO (selectivity \%)} = \frac{\text{Yield}_{(\text{CO})} \times 2}{\text{Yield}_{(\text{CO})} \times 2 + \text{Yield}_{(\text{CH}_4)} \times 8} \times 100\%$$

$$\text{CH}_4 \text{ (selectivity \%)} = \frac{\text{Yield}_{(\text{CH}_4)} \times 8}{\text{Yield}_{(\text{CO})} \times 2 + \text{Yield}_{(\text{CH}_4)} \times 8} \times 100\%$$

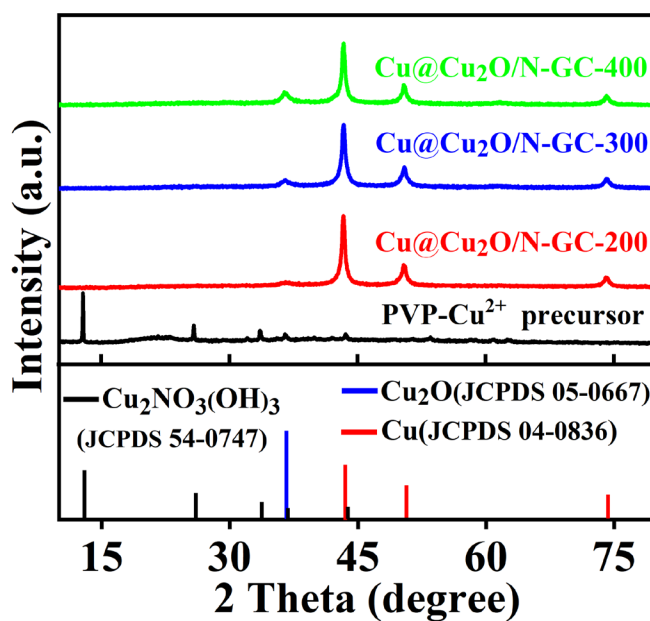
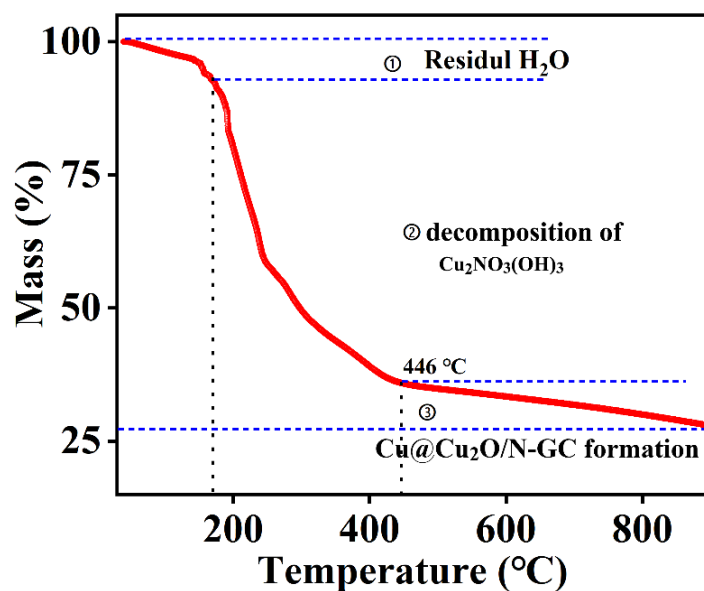
Apparent Quantum Yield values measurement.

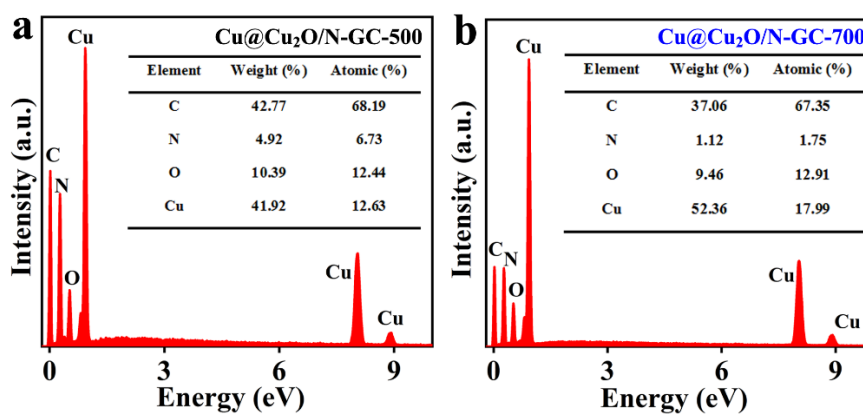
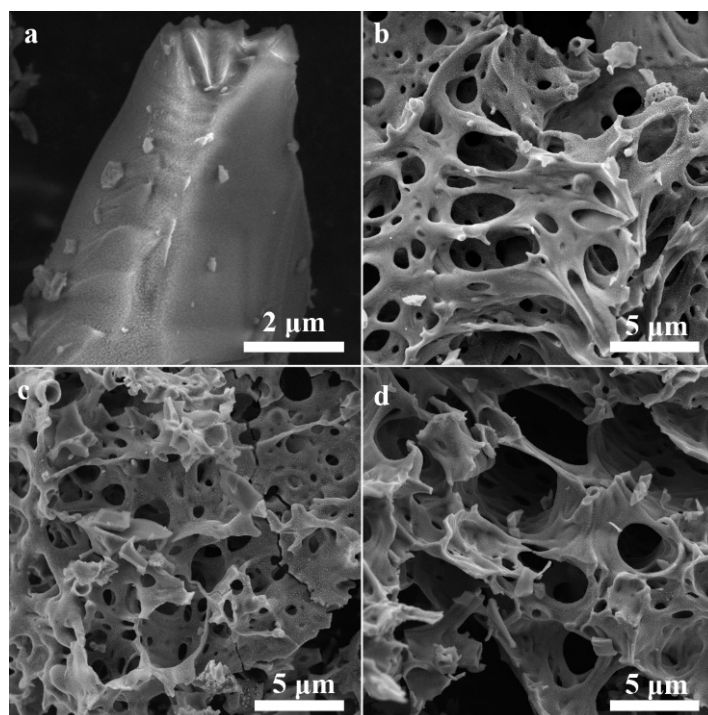
Apparent quantum Yield (AQY) values were calculated using the following equation:^{2,3}

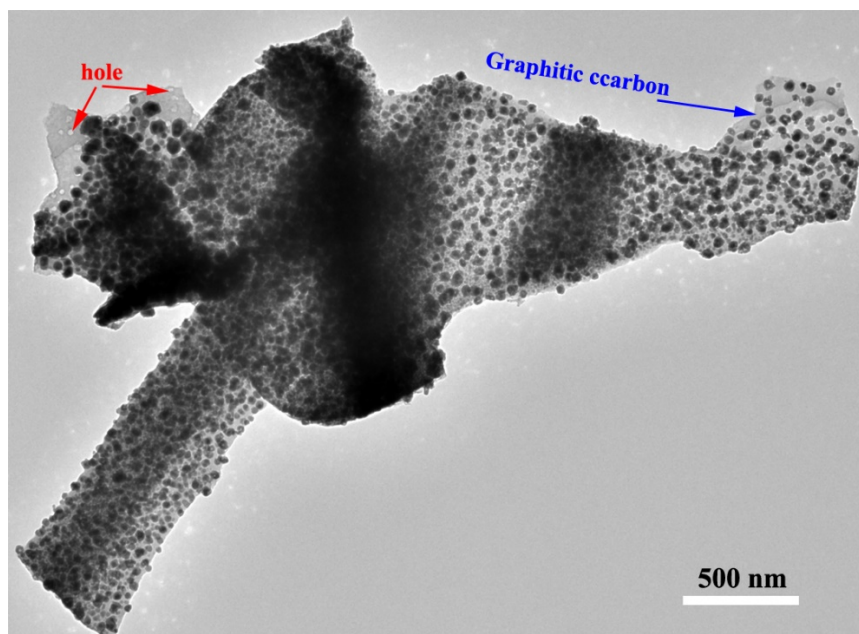
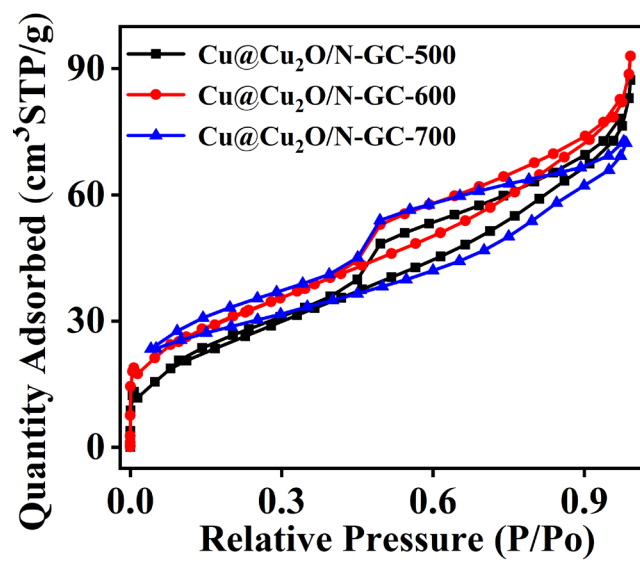
$$\text{AQY} = \frac{\text{number of reacted electrons}}{\text{number of incident photons}} \times 100\%$$

The external quantum efficiency values for CO and CH₄ generation were determined at 420 nm using a band pass filter with the same photochemical experimental setup. The flux of incident

photons from the power was measured by a power meter (PL-MW2000, Photoradiometer). The lamp intensity at 420 nm was measured to be $3.97 \text{ W}\cdot\text{cm}^2$, the illuminated area was 28.71 cm^2 , and the incident photons flux was calculated to be 4777.92 h^{-1} .







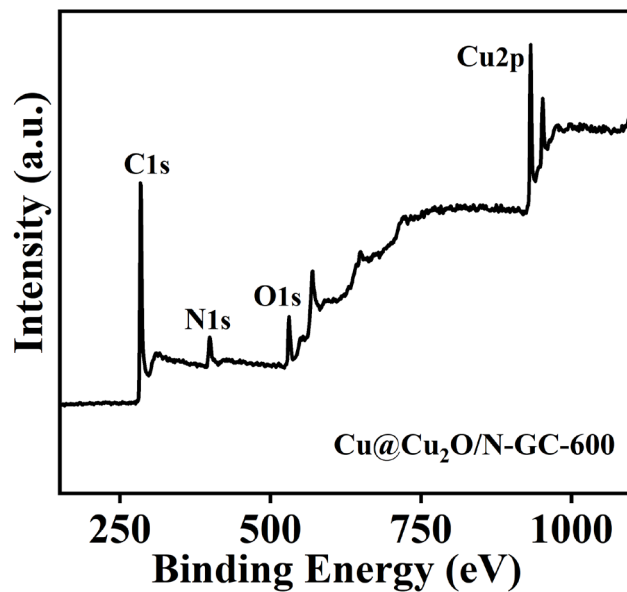
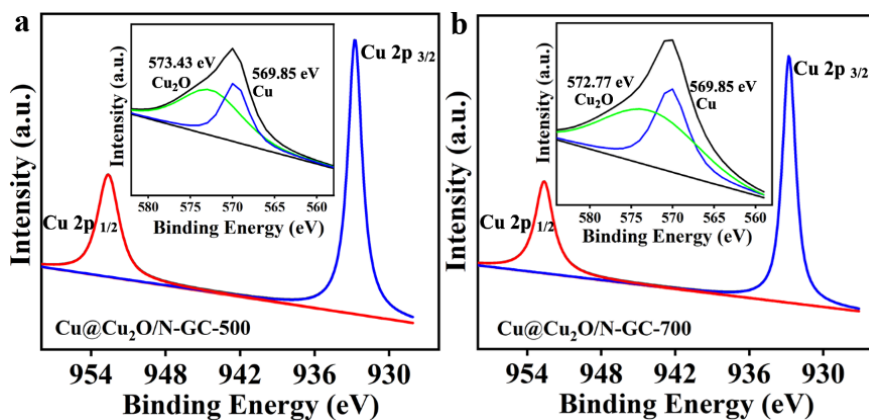
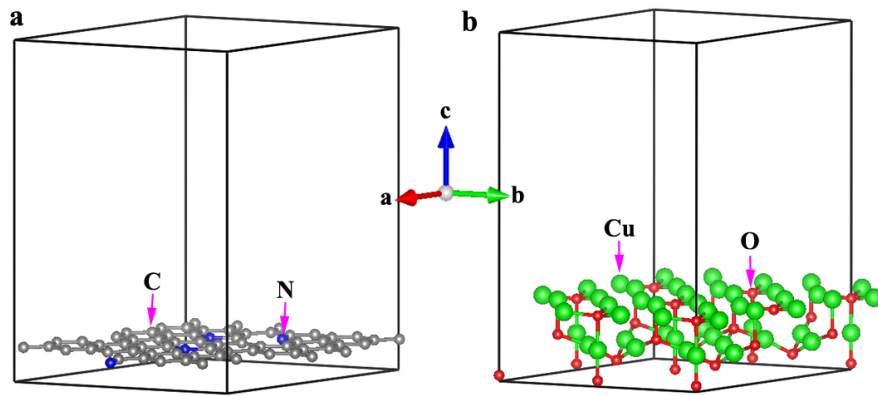
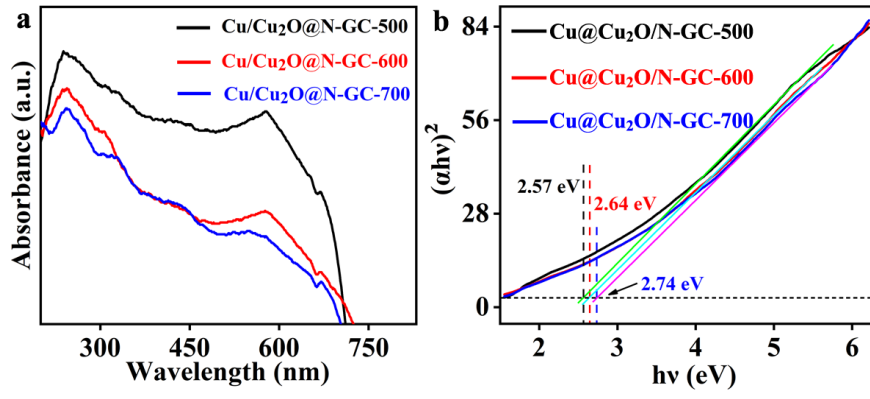
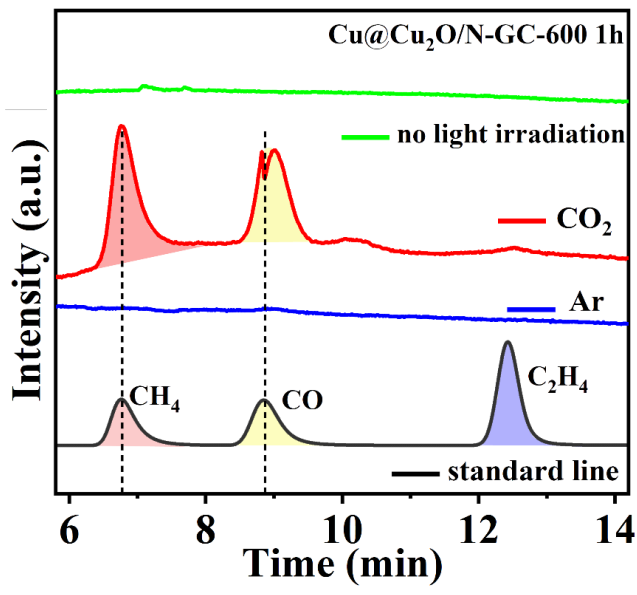
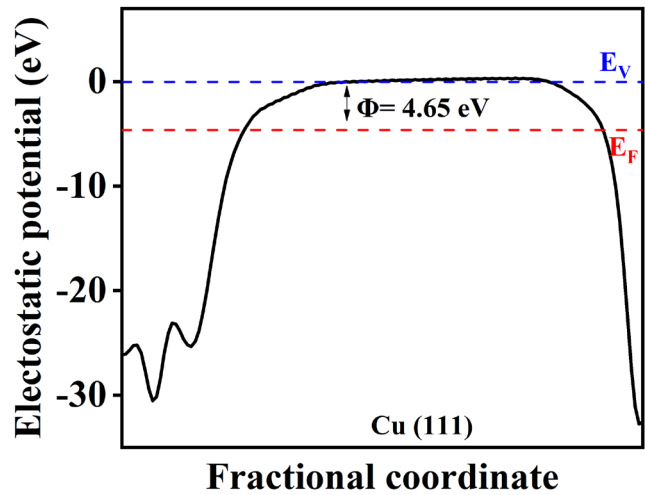
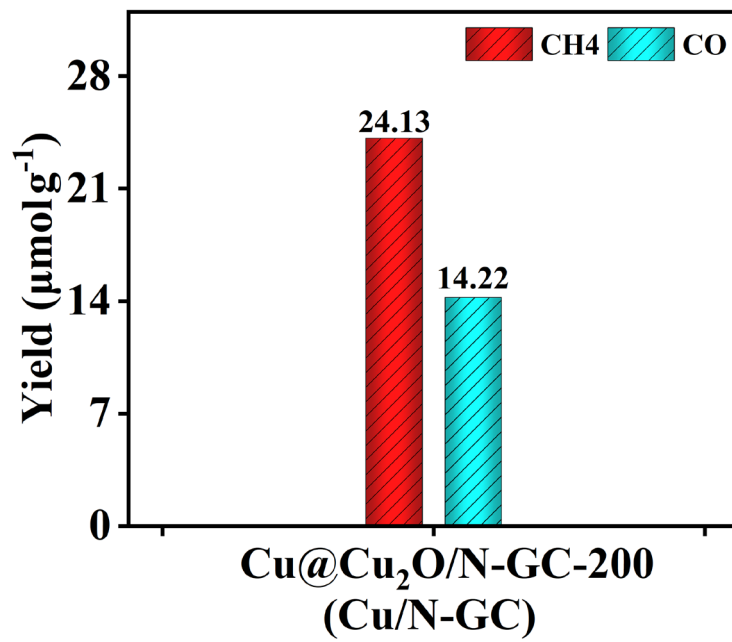
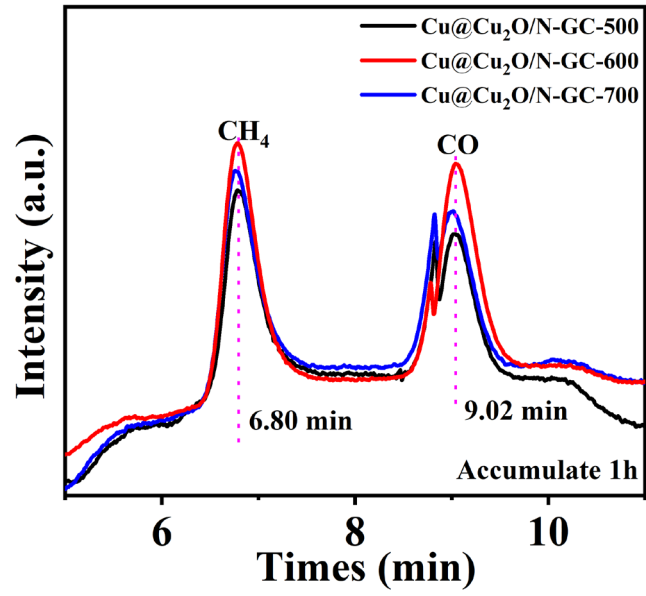


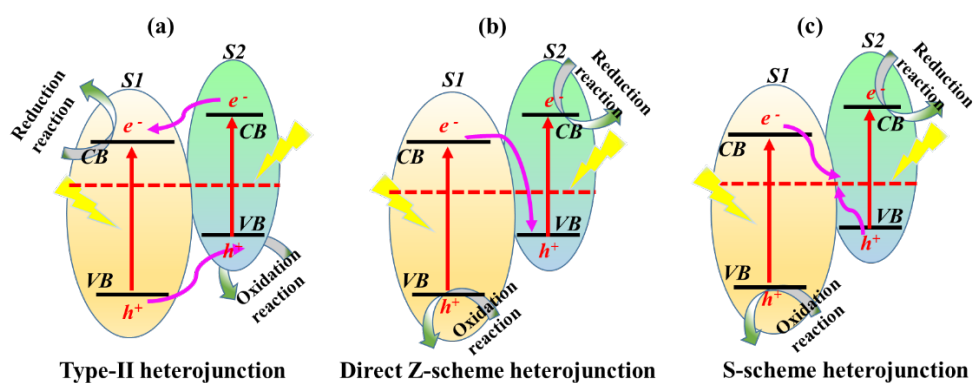
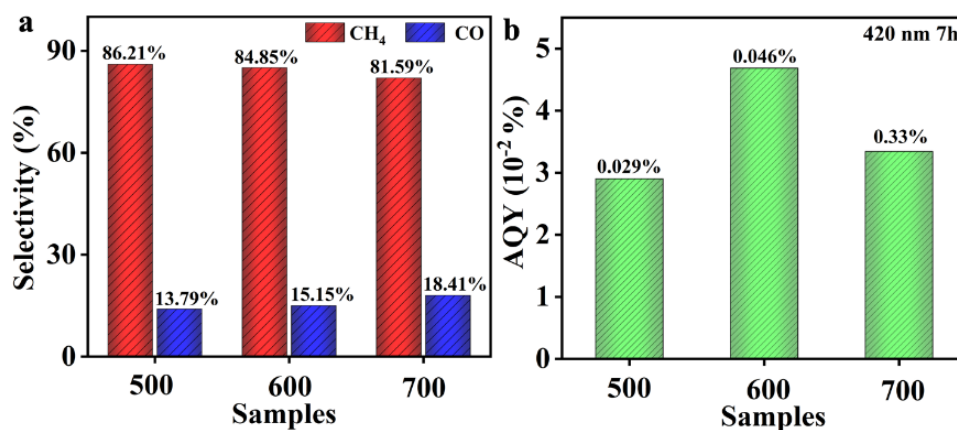
Figure S7 XPS survey spectra of the Cu@Cu₂O/N-GC-600











As shown in **Figure S16a**, two semiconductors S1 and S2 with a staggered band structure configuration can form the type II heterojunction, both the CB and VB edges of S2 are higher than those of S1. When the photocatalytic system is excited by light, the photogenerated electrons in the CB of S2 can transfer to the CB of S1 and the photogenerated holes in the VB of S1 can

transfer to the VB of S2 due to the potential difference of CB and VB between the two semiconductors.⁴

In a direct Z-scheme heterojunction (**Figure S16b**), S1 and S2 are excited by light irradiation, and the photogenerated electrons in the CB of S1 can directly recombine with the holes in the VB of S2. Thus, the photogenerated electrons in the CB of S2 and photogenerated holes in the VB of S1 are spatially separated and also maintain their initial strong redox capability, which enhances the efficiency of the redox reactions.³

In an S-scheme heterojunction (**Figure S16c**), when S1 and S2 come into contact, their Fermi energy should be aligned to the same level. This leads to an upward and downward shift in the Fermi levels of S1 and S2, respectively. The band bending and Coulombic attraction facilitate the recombination of the photogenerated electrons in the CB of S1 and holes in the VB of S2 at the interface region. The active photogenerated electrons and holes are reserved in the CB of S2 and VB of S1, respectively, while the useless photogenerated charge carriers (electrons in CB of S1 and holes in VB of S2) are recombined, resulting a strong redox potential.⁵

As shown in **Figure 9b**, two semiconductors Cu₂O and N-GC with a staggered band structure configuration can form the S-scheme heterojunction, both the CB and VB edges of N-GC are higher than those of Cu₂O and Cu. When the Cu@Cu₂O/N-GC system is excited by light, the photogenerated electrons in the CB of Cu₂O can transfer to the VB of N-GC. As a result, the photogenerated electrons and holes are spatially separated in Cu₂O and N-GC, respectively. The photogenerated electrons in N-GC is used to reduce CO₂. Since the positions of CB of Cu₂O are close to the VB of N-GC, the excited electrons on CB of Cu₂O can further capture the photogenerated holes in the VB of N-GC. The photogenerated electrons and holes in Cu₂O and

N-GC can be spatially separated, which is possibly attributed to the formation of a S-scheme semiconductor heterojunction.⁵

Table S1 Temperature changes during the photocatalytic CO₂ RR under visible light irradiation

Test times (h)	0	1	2	3	4	5	6	7
Temperature (°C)	24.0	24.3	24.6	24.9	25.0	25.1	25.3	25.3

Table S2 BET results of the Cu@Cu₂O/N-GC catalysts.

Samples	S _{BET} (m ² /g)	pore sizes (nm)	pore volumes(cm ³ /g)
Cu@Cu ₂ O/N-GC-500	37.72	3.43	0.025
Cu@Cu ₂ O/N-GC-600	89.86	3.80	0.079
Cu@Cu ₂ O/N-GC-700	49.01	3.43	0.028

Table S3 Fitting parameters for TRPL curves recorded for Cu@Cu₂O/N-GC-500, Cu@Cu₂O/N-GC-600 and Cu@Cu₂O/N-GC-700 samples.

Sample	τ ₁ (ns)	% percentage	τ ₂ (ns)	% percentage	τ _{avrg.} (ns)
Cu@Cu₂O/N-GC-500	0.37	0.64	0.36	0.36	0.36
Cu@Cu₂O/N-GC-600	0.42	0.62	0.42	0.38	0.41
Cu@Cu₂O/N-GC-700	0.44	0.62	0.44	0.38	0.44

Table S4 Cu 2p peak position and peak area ratio (Cu₂O/Cu) of samples

Sample	Cu@Cu ₂ O/N-GC-500		Cu@Cu ₂ O/N-GC-600		Cu@Cu ₂ O/N-GC-700	
Peak	Cu ₂ O	Cu	Cu ₂ O	Cu	Cu ₂ O	Cu
Peak position (eV)	573.43	569.85	573.60	569.20	572.77	570.21
Peak area ratio	1.18		1.25		1.51	
Cu ₂ O/Cu	1.18		1.25		1.51	

Table S5. Comparison of the gas photocatalytic performance for the Cu₂O-based photocatalysts reported in the literature.

metal oxide Photocatalysts	Product and Yield	Stability (h)	Ref.
Cu₂O/Ti₃C₂ MXene	CO (17.55 μmol g ⁻¹ h ⁻¹)	17	6
	CH ₄ (0.96 μmol g ⁻¹ h ⁻¹)		
Cu₂O@Cu	CH ₄ (0.137 μmol cm ⁻²)	24	7
Cu₂O/CeO₂	CO (~1,2 μmol g ⁻¹ h ⁻¹)	30	8
g-C₃N₄ foam/Cu₂O QDs	CO 8.12 μmol g ⁻¹ h ⁻¹	25	9
	CH ₄ (~0.1 μmol cm ⁻²)		
Cu₂O decorated WO₃	CH ₄ (~10 μmol h ⁻¹ g ⁻¹)	24	10
Cu@Cu₂O/N-GC	CO (27.78 μmol g ⁻¹) CH ₄ (38.89 μmol g ⁻¹)	42	—
This work	μmol g ⁻¹)		

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